

## Modular-Design Femtosecond Lasers for Industry and Science



Tunable pulse duration, 100 fs – 20 ps

Maximum pulse energy of up to 4 mJ

Down to < 100 fs right at the output

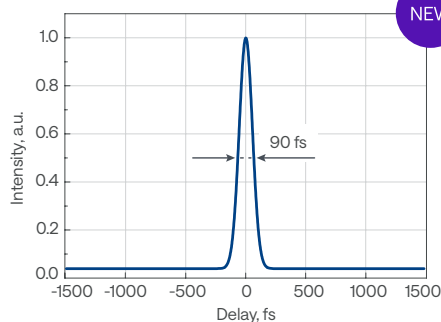
Pulse-on-demand and BiBurst for pulse control

Up to 5<sup>th</sup> harmonic or tunable extensions

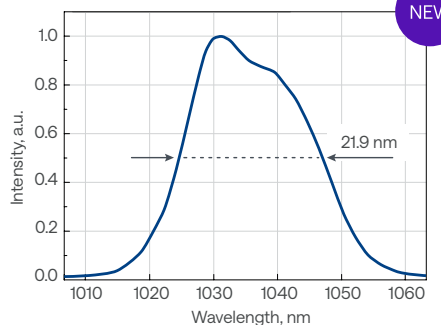
CEP stabilization or repetition rate locking

Thermally-stabilized and sealed design

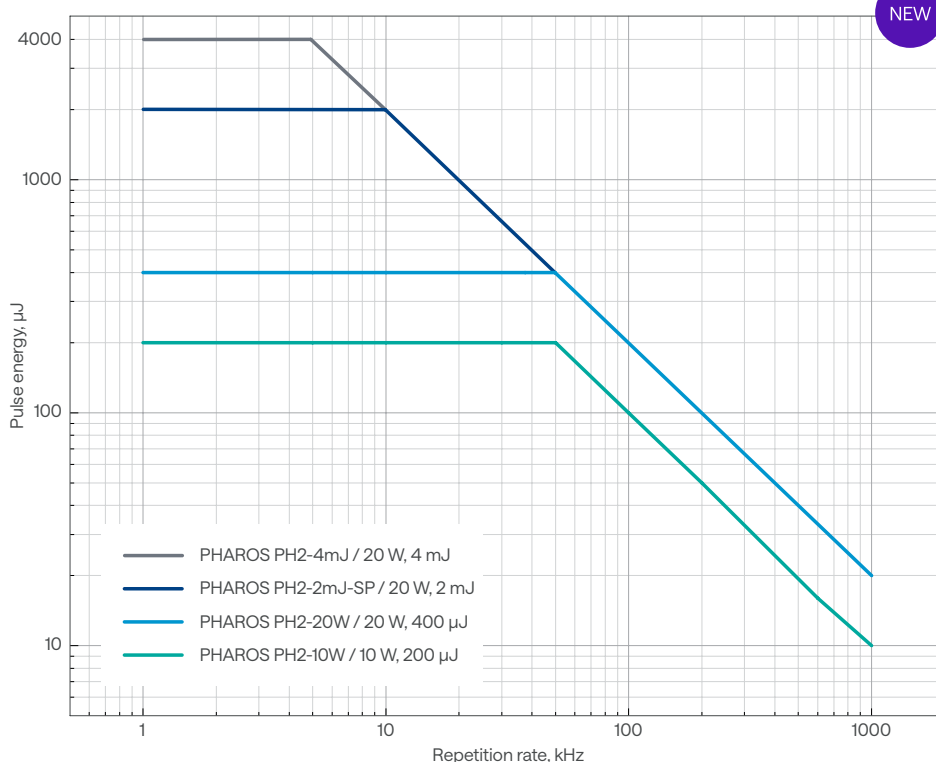
PHAROS-PH2-UP  
Typical pulse duration



PHAROS-PH2-UP  
Typical spectrum



PHAROS  
Pulse energy vs fundamental repetition rate



# Specifications

NEW

Model	PH2-10W	PH2-20W-SP		PH2-4mJ	PH2-UP
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## OUTPUT CHARACTERISTICS

Center wavelength <sup>1)</sup>	1030 ± 10 nm				
Maximum output power	10 W	20 W			
Pulse duration <sup>2)</sup>	< 290 fs	< 190 fs		< 450 fs <sup>3)</sup>	< 100 fs
Pulse duration tuning range	290 fs – 10 ps (20 ps on request)	190 fs – 10 ps (20 ps on request)		450 fs – 10 ps	100 fs – 10 ps
Maximum pulse energy	0.2 mJ	0.4 mJ	1 mJ	2 mJ	4 mJ
Repetition rate	Single-shot – 1 MHz				
Pulse selection	Single-shot, pulse-on-demand, any fundamental repetition rate division				
Polarization	Linear, horizontal				
Beam quality, M <sup>2</sup>	< 1.2		< 1.3		< 1.2
Beam diameter <sup>4)</sup>	3.3 ± 0.3 mm	4.0 ± 0.5 mm	4.5 ± 0.5 mm	6.6 ± 0.7 mm	4.5 ± 0.5 mm
Beam pointing stability	< 20 µrad/°C				
Pre-pulse contrast	< 1: 1000				
Post-pulse contrast	< 1: 200				
Pulse-to-pulse energy stability, 24 h <sup>5)</sup>	< 0.5%				
Long-term power stability, 100 h <sup>5)</sup>	< 0.5%				

## MAIN OPTIONS

Oscillator output <sup>6)</sup>	1 – 7 W, 50 – 250 fs, ≈ 1035 nm, ≈ 76 MHz				
Harmonic generator <sup>7)</sup>	515 nm, 343 nm, 257 nm, or 206 nm				
Optical parametric amplifier <sup>8)</sup>	320 – 10000 nm				
BiBurst option	Tunable GHz and MHz burst with burst-in-burst capability				
CEP stabilization	Optional				
Repetition rate locking					

## PHYSICAL DIMENSIONS

Laser head (L × W × H) <sup>9)</sup>	730 × 419 × 230 mm	827 × 492 × 250 mm	730 × 419 × 230 mm
Chiller (L × W × H)	590 × 484 × 267 mm		
24 V DC power supply (L × W × H) <sup>9)</sup>	280 × 144 × 49 mm		

## ENVIRONMENTAL & UTILITY REQUIREMENTS

Operating temperature	15 – 30 °C (air conditioning recommended)		
Relative humidity	< 80% (non-condensing)		
Electrical requirements	Laser	100 V AC, 12 A – 240 V AC, 5 A, 50 – 60 Hz	
	Chiller	100 – 230 V AC, 50 – 60 Hz	
Rated power	Laser	1000 W	
	Chiller	1400 W	
Power consumption	Laser	600 W	
	Chiller	1000 W	

<sup>1)</sup> Precise wavelengths for specific models are available on request.

<sup>2)</sup> Assuming Gaussian pulse shape.

<sup>3)</sup> Pulse duration can be reduced to < 250 fs if pulse peak intensity of > 50 GW/cm<sup>2</sup> is tolerated by customer setup.

<sup>4)</sup> FW 1/e<sup>2</sup>, measured at laser output, using maximum pulse energy.

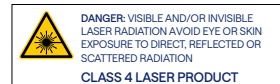
<sup>5)</sup> Under stable environmental conditions. Expressed as normalized root mean squared deviation (NRMSD).

<sup>6)</sup> Available simultaneously. Contact sales@lightcon.com for details or customized solutions.

<sup>7)</sup> Integrated. For external harmonic generator, refer to HIRO.

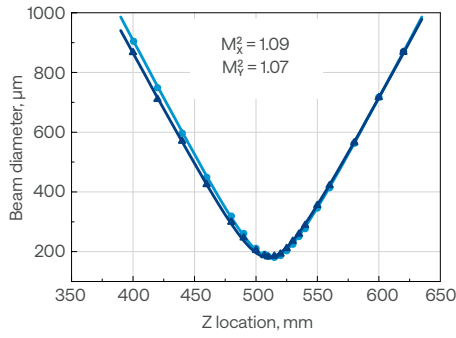
<sup>8)</sup> Integrated. For more options and OPAs for -4mJ and -UP models, refer to www.lightcon.com

<sup>9)</sup> Dimensions depend on laser configuration and integrated options.

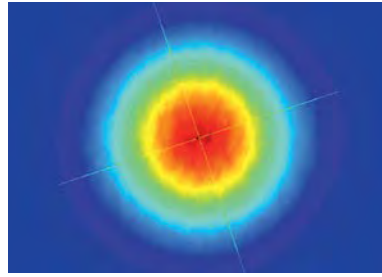


## Beam properties

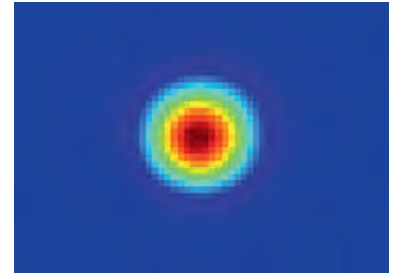
**PHAROS**  
Typical  $M^2$  measurement data



**PHAROS**  
Typical near-field beam profile

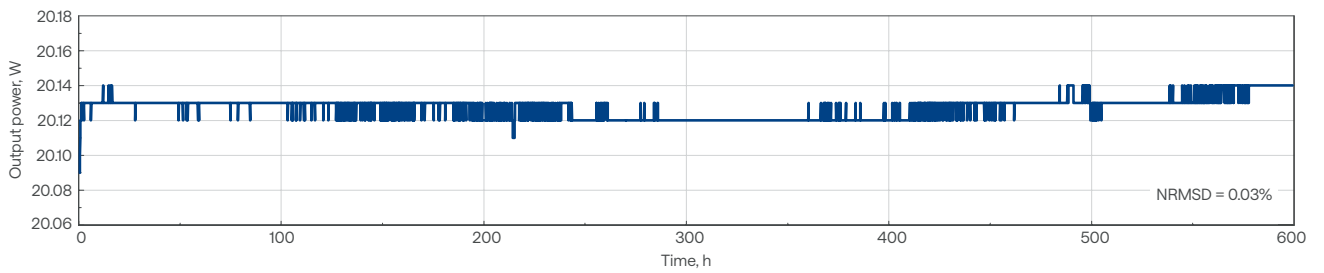


**PHAROS**  
Typical far-field beam profile

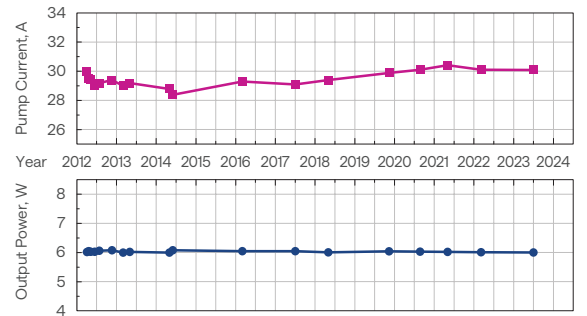
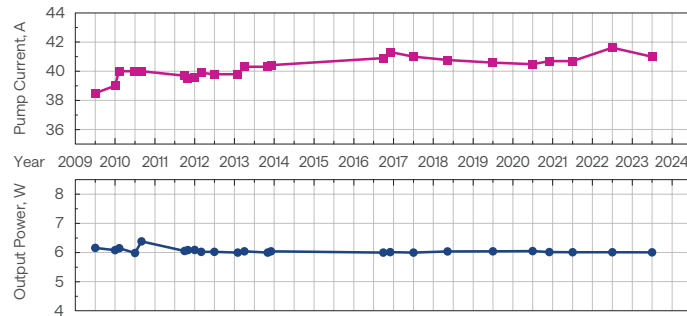


## Stability measurements

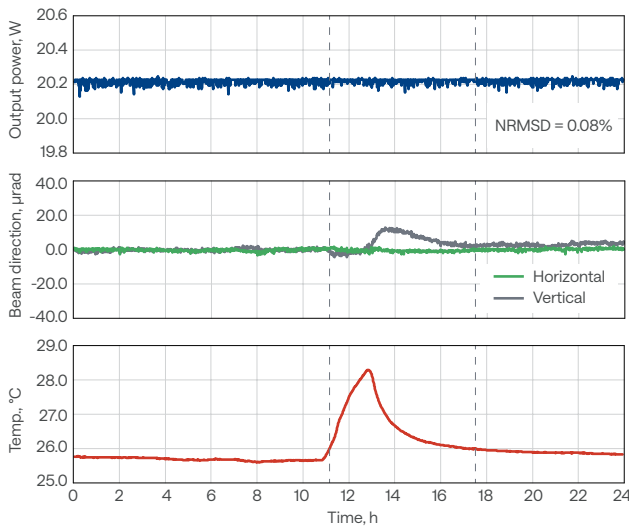
**PHAROS**  
Long-term power stability



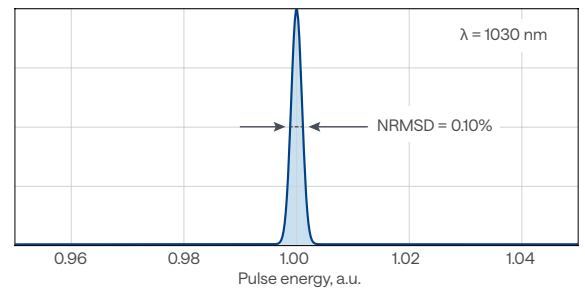
Output power of industrial-grade **PHAROS** lasers operating 24/7 and the current of the pump diodes over the years



**PHAROS** output power and the stability of beam direction with power lock enabled, across varying environmental conditions



**PHAROS**  
Typical pulse-to-pulse energy stability



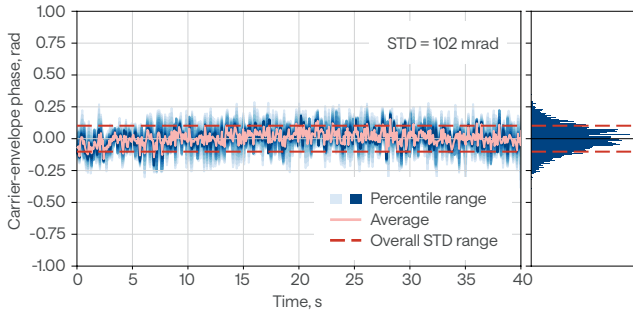
## CEP stabilization

PHAROS lasers can be equipped with feedback electronics for carrier-envelope phase (CEP) stabilization of the output pulses. The carrier-envelope offset (CEO) of the PHAROS oscillator is actively locked to 1/4<sup>th</sup> of the repetition rate with a < 100 mrad standard deviation. The CEP stable pulses from the

synchronized amplifier have a < 350 mrad standard deviation. The CEP drift occurring inside the amplifier and the user's setup can be compensated with an out of loop f-2f interferometer, which is a part of the complete PHAROS active CEP stabilization package.

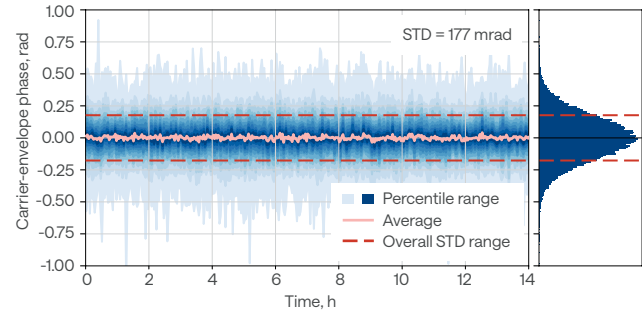
### PHAROS

Short-term CEP stability operating at 200 kHz repetition rate



### PHAROS

Long-term CEP stability operating at 200 kHz repetition rate

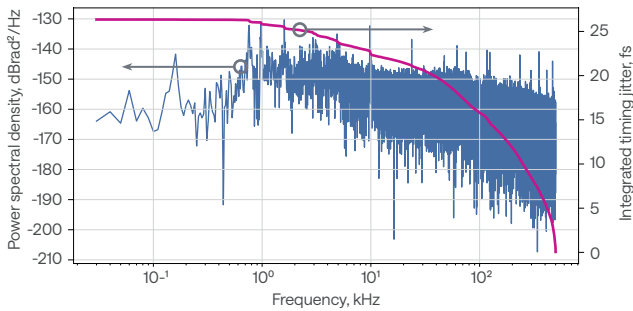


## Repetition rate locking

The oscillator of PHAROS laser can be customized for repetition rate locking applications. Coupled with the necessary feedback electronics, the repetition rate is synchronized to an external RF source using the two piezo stages installed inside the cavity.

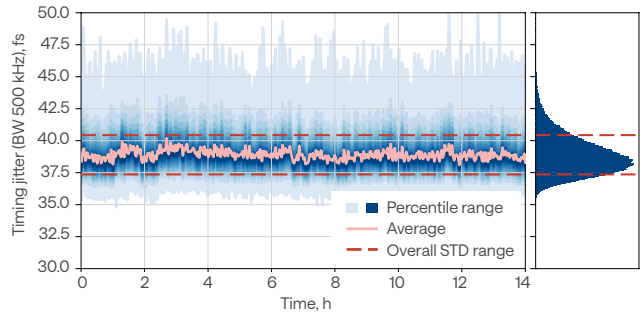
The repetition rate locking system can assure an integrated timing jitter of less than 200 fs for RF reference frequencies larger than 500 MHz. Continuous phase shifting is available on request.

Phase noise data of PHAROS oscillator locked to a 2.8 GHz RF source



Timing jitter stability over 14 h

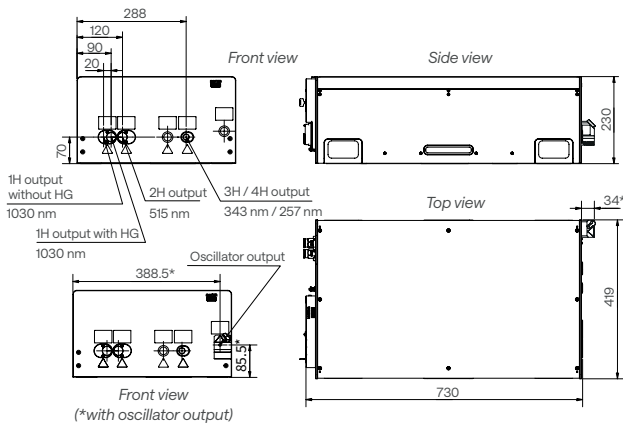
PHAROS oscillator locked to a 2.8 GHz RF source



## Drawings

PHAROS-PH2-730 drawing.

PH2 or PH2-SP with FEC, BiBurst, or harmonics; also, PH2-UP without harmonics



PHAROS-PH2-827 drawing

PH2 with -HE harmonics, PH2-4mJ, or PH2-UP with harmonics

